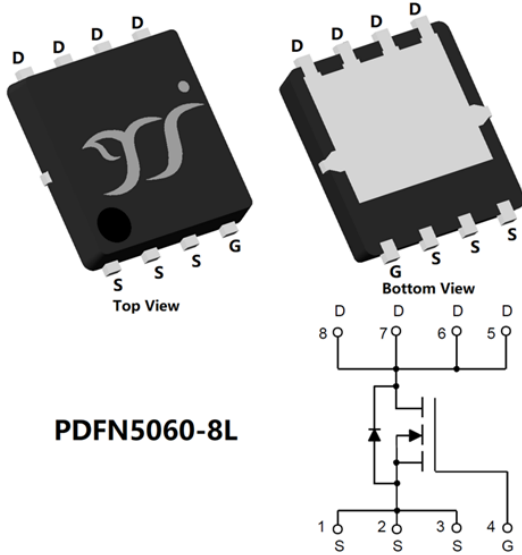


N-Channel Enhancement Mode Field Effect Transistor



Product Summary

- V_{DS} 60V
- I_D 280A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) $<1.4m\Omega$
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- BMS
- Motor drive

Limiting Values

Parameter	Conditions		Symbol	Min	Max	Unit
Drain-Source Voltage			V _{DS}	-	60	V
Gate-Source Voltage			V _{GS}	-20	20	
Continuous Drain Current (Note 1,2)	Steady-State	T _A =25°C,V _{GS} =10V	I _D	-	30.6	A
		T _A =100°C,V _{GS} =10V		-	21.7	
Continuous Drain Current (Note 1,3)	Steady-State	T _C =25°C,V _{GS} =10V,Chip limitation		-	280	
		T _C =100°C,V _{GS} =10V		-	198	
Pulsed Drain Current	T _C =25°C,t _p ≤10μs		I _{DM}	-	1120	
Maximum Body-Diode Continuous Current	T _C =25°C		I _S	-	184	
Avalanche Energy (non-repetitive)	T _J =25°C,V _G =10V,R _G =25Ω,L=1mH,I _{AS} =49A		EAS	-	1200.5	mJ
Total Power Dissipation (Note 1,2)	Steady-State	T _A =25°C	P _D	-	2.6	W
		T _A =100°C		-	1.3	
Total Power Dissipation (Note 1,3)	Steady-State	T _C =25°C		-	220.5	
		T _C =100°C		-	110.3	
Junction and Storage Temperature Range			T _J ,T _{STG}	-55	175	°C

Thermal Resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	Steady-State	$R_{\theta JA}$	-	57	$^\circ C/W$
Thermal Resistance Junction-to-Case	Steady-State	$R_{\theta JC}$	-	0.68	



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■ Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=1mA, T_J=25^{\circ}C$	60	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V, T_J=25^{\circ}C$	-	-	1	μA
		$V_{DS}=60V, V_{GS}=0V, T_J=125^{\circ}C$	-	-	250	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V, T_J=25^{\circ}C$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A, T_J=25^{\circ}C$	2	2.8	3.6	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=50A, T_J=25^{\circ}C$	-	1.15	1.4	m Ω
Diode Forward Voltage	V_{SD}	$I_S=50A, V_{GS}=0V, T_J=25^{\circ}C$	-	0.8	1.2	V
Gate Resistance	R_G	$f=1MHz, T_J=25^{\circ}C$	-	2.5	-	Ω
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=30V, V_{GS}=0V, f=1MHz, T_J=25^{\circ}C$	-	5254	-	pF
Output Capacitance	C_{oss}		-	1640	-	
Reverse Transfer Capacitance	C_{rss}		-	124	-	
Total Gate Charge	Q_g	$V_{GS}=10V, V_{DS}=30V, I_D=50A, T_J=25^{\circ}C$	-	73.1	-	nC
Gate-Source Charge	Q_{gs}		-	22.3	-	
Gate-Drain Charge	Q_{gd}		-	14.3	-	
Output charge (Note 4)	Q_{oss}	$V_{DS}=30V, V_{GS}=0V, T_J=25^{\circ}C$	-	103	-	nC
Reverse Recovery Charge	Q_{rr}	$I_F=50A, di/dt=100A/\mu s, V_{GS}=0V, V_R=30V, T_J=25^{\circ}C$	-	36.3	-	nC
Reverse Recovery Time	t_{rr}		-	38.3	-	ns
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=10V, V_{DS}=30V, I_D=50A, R_{GEN}=3\Omega, T_J=25^{\circ}C$	-	19.9	-	ns
Turn-on Rise Time	t_r		-	85.3	-	
Turn-off Delay Time	$t_{D(off)}$		-	52.5	-	
Turn-off Fall Time	t_f		-	44.6	-	

Note:

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
2. The value of $R_{\theta JA}$ is measured with the device mounted on the 40mm*40mm*1.1mm single layer FR-4 PCB board with 1 in² pad of 2oz. Copper, in the still air environment with $T_A=25^{\circ}C$. The maximum allowed junction temperature of 175 $^{\circ}C$. The value in any given application depends on the user's specific board design.
3. Thermal resistance from junction to soldering point (on the exposed drain pad).
4. Defined by design. Not subject to production test.



■ Typical Electrical and Thermal Characteristics Diagrams

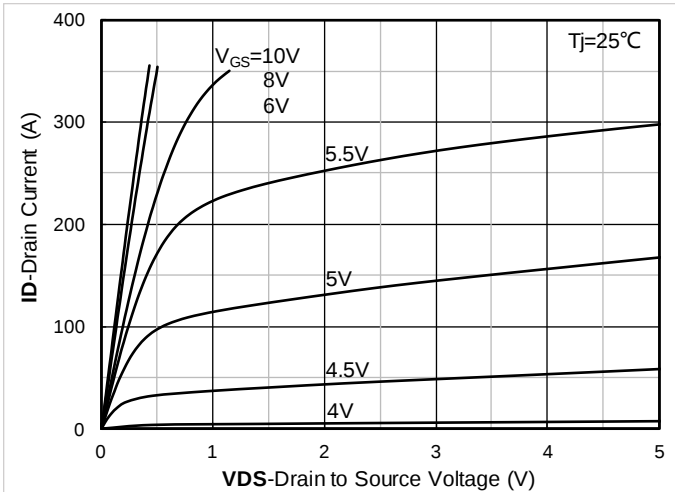


Figure 1. Output Characteristics; typical values

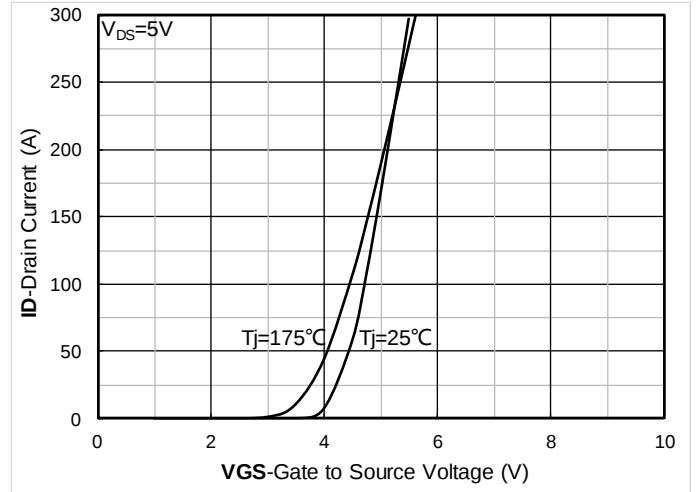


Figure 2. Transfer Characteristics; typical values

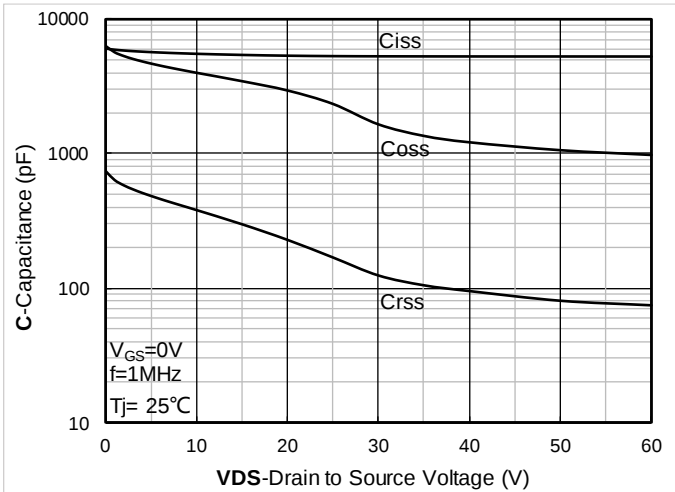


Figure 3. Capacitance Characteristics; typical values

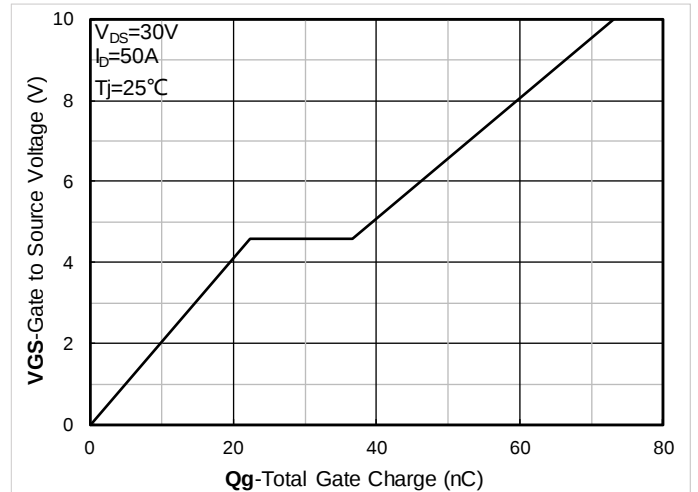


Figure 4. Gate Charge; typical values

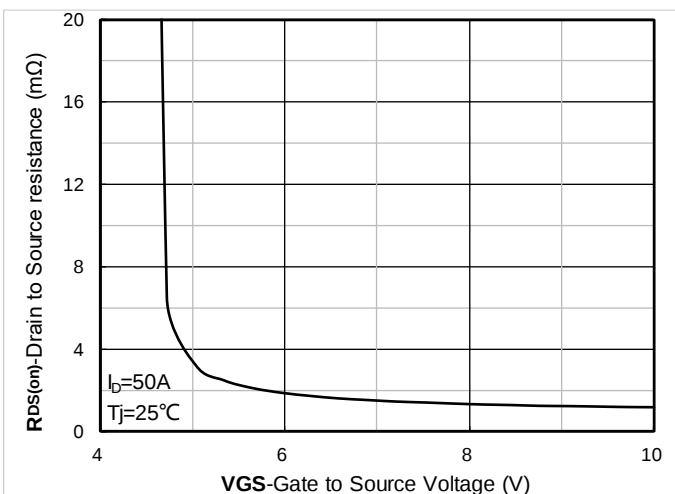


Figure 5. On-Resistance vs. Gate to Source Voltage; typical values

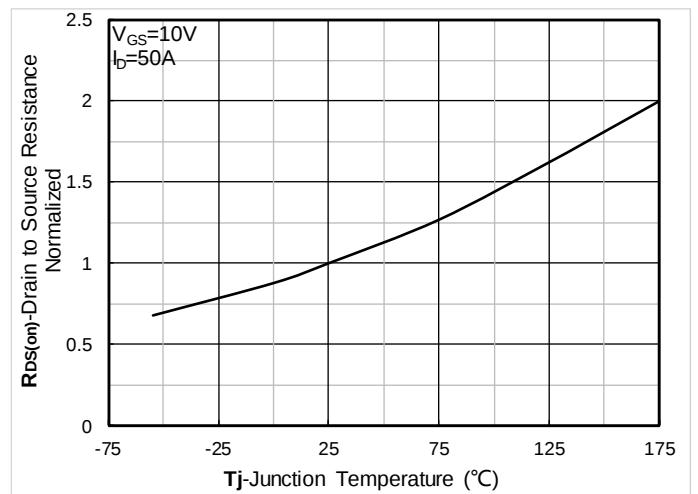


Figure 6. Normalized On-Resistance

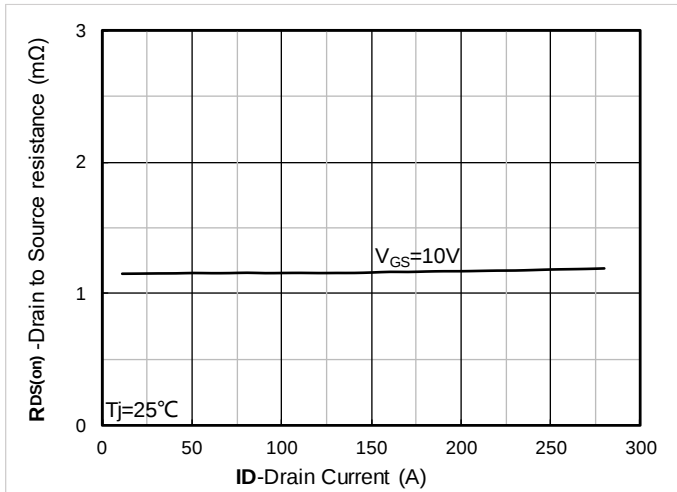


Figure 7. $R_{DS(on)}$ vs. Drain Current; typical values

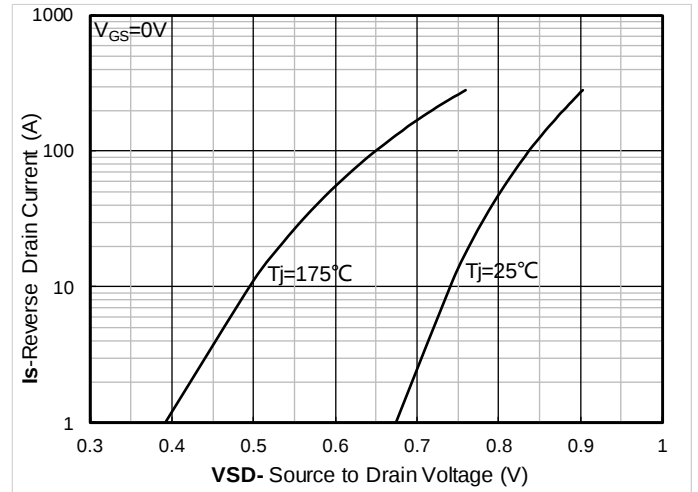


Figure 8. Forward characteristics of reverse diode; typical values

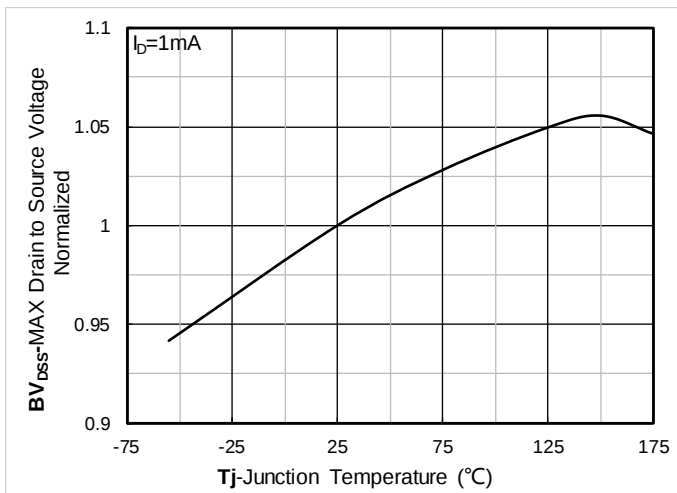


Figure 9. Normalized breakdown voltage

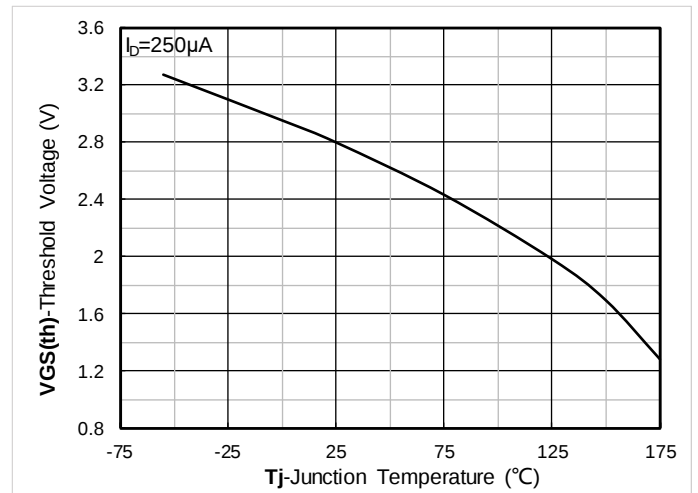


Figure 10. Gate Threshold voltage; typical values

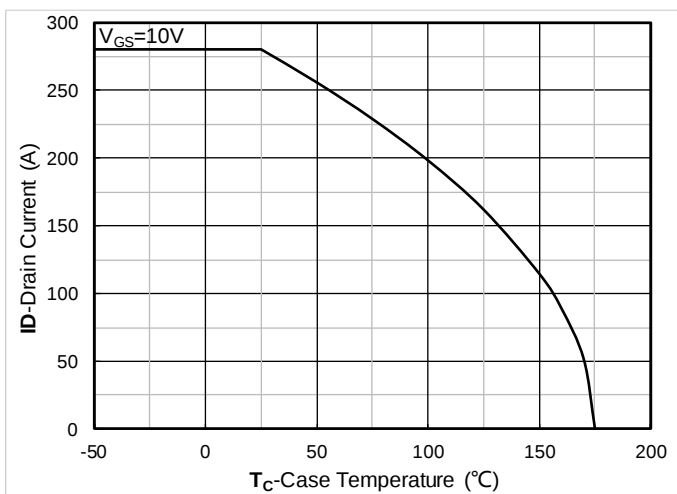


Figure 11. Current dissipation

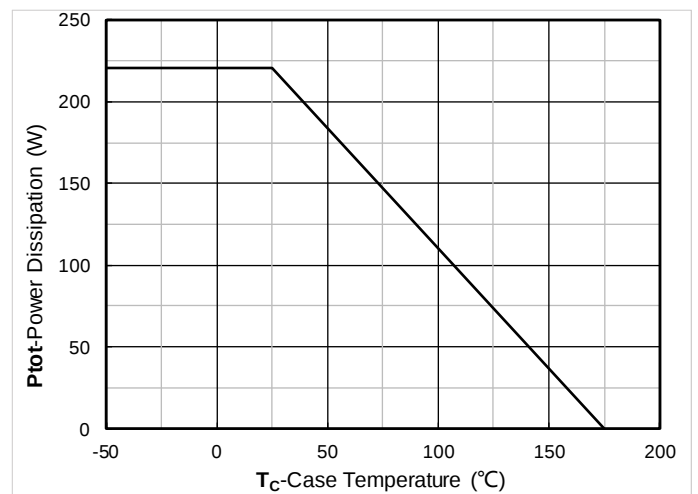


Figure 12. Power dissipation

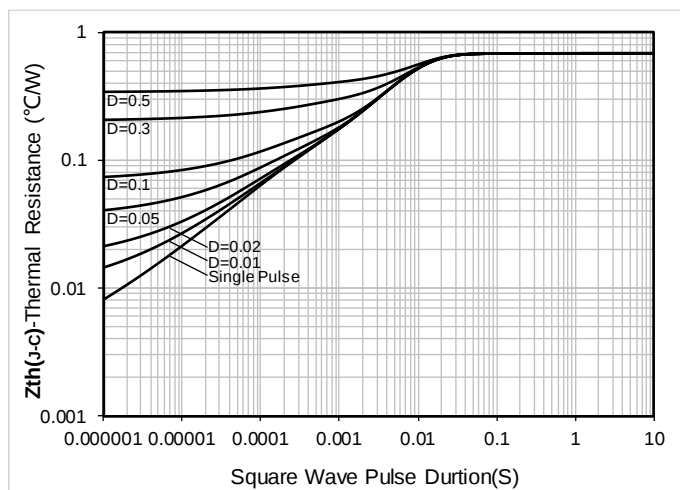


Figure 13. Maximum Transient Thermal Impedance

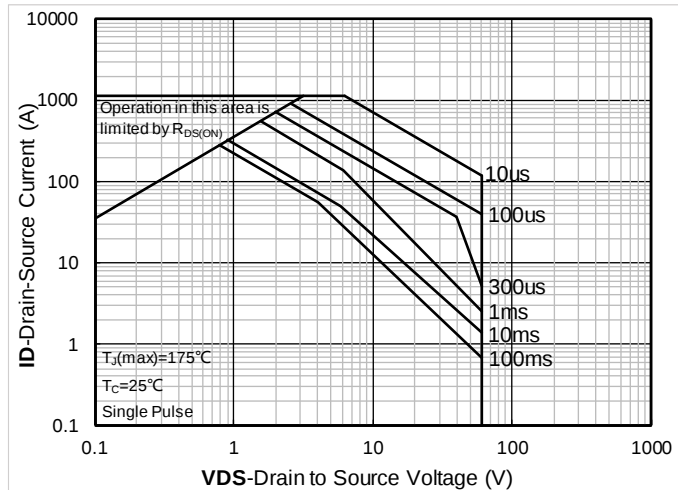
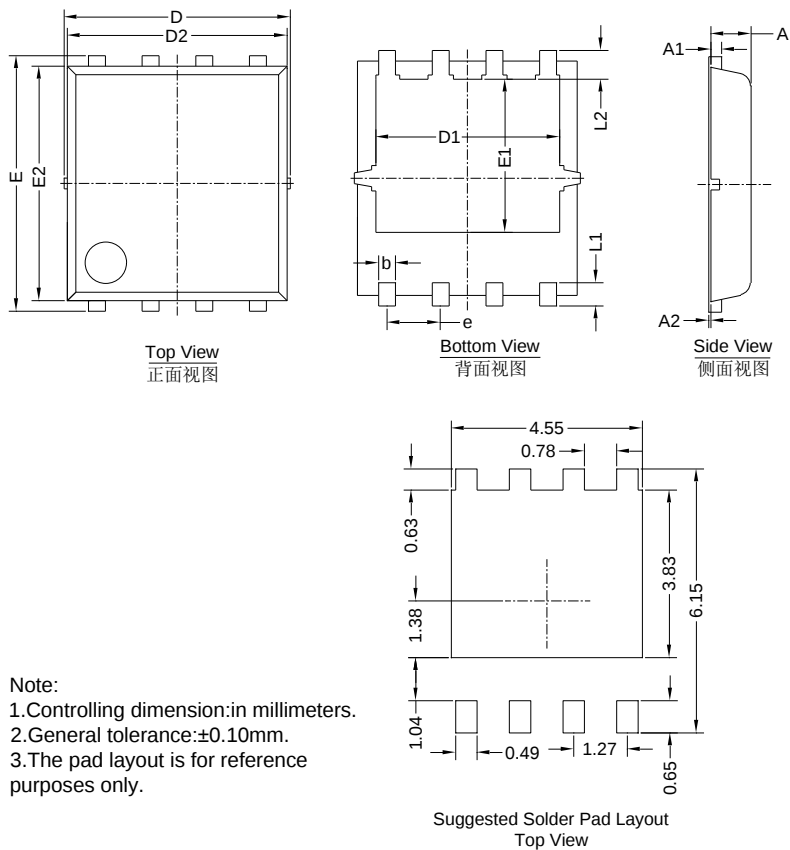


Figure 14. Safe Operation Area



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■ PDFN5060-8L-D-0.95MM Package information

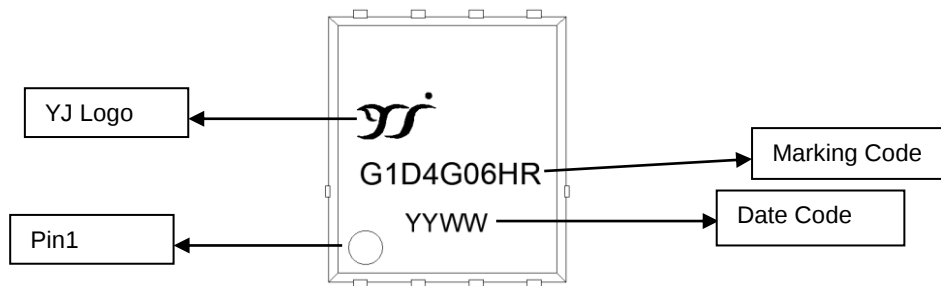


SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	5.15	5.35	5.55
E	5.95	6.05	6.15
A	0.85	0.95	1.05
A1	0.203 BSC		
A2			0.08
D1	4.25	4.35	4.45
E1	3.525	3.625	3.725
D2		5.20	
E2		5.55	
L1	0.45	0.55	0.65
L2	0.68 BSC		
b	0.3	0.4	0.5
e	1.27 BSC		



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■ Marking Information



Note:

1. All marking is at middle of the product body
2. All marking is in laser printing
3. YYWW is date code, "YY" is year, "WW" is week
4. Body color: Black



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